10/7/8652



THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent of

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NAKAMURA et al

Atty. Ref.:

CC-160-399

Patent No. 7,166,874

Issued: January 23, 2007

For: NITRIDE SEMICONDUCTOR WITH ACTIVE LAYER OF

QUANTUM WELL STRUCTURE WITH INDIUM-CONTAINING NITRIDE SEMICONDUCTOR

November 21, 2007

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

REQUEST FOR A CERTIFICATE OF CORRECTION

The patentee in the above-identified patent hereby requests that the Patent and Trademark Office issue an official Certificate of Correction pursuant to 37 C.F.R. § 1.323 for the following mistake made by the applicant.

Column 19, line 62, "that that" should be "than that".

Since the error arose on the part of the patentee, a check in the amount of \$100.00 is submitted herewith securing issuance of the Certificate.

Attached hereto is a draft Official Certificate of Correction for use by the Patent and Trademark Office correcting the above-identified matter.

The Commissioner is hereby authorized to charge any <u>deficiency</u> in the fee(s) filed, or asserted to be filed, or which should have been filed herewith (or with any paper hereafter filed in this application by this firm) to our **Account No. 14-1140**. A <u>duplicate</u> copy of this sheet is attached. 11/23/2007 SZEWDIE1 00000066 7168874

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NAKAMURA et al **Patent No.** 7,166,874

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Respectfully submitted,

NIXON & VANDERHYE P.C.

By:

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MOV 27 2007

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UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO.

: 7,166,874

DATED

: January 23, 2007

INVENTOR(S)

: NAKAMURA et al

It is certified that error appears in the above-identified patent and that said letters patent is hereby corrected as shown below:

Column 19, line 62,

"that that" should be "than that".

MAILING ADDRESS OF SENDER:

Chris Comuntzis NIXON & VANDERHYE P.C. 901 North Glebe Road, 11th Floor Arlington, Virginia 22201

Form PTO 1050 (Rev. 2-93)

PATENT NO.

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